# BPW76A, BPW76B

## Vishay Semiconductors



## Silicon NPN Phototransistor, RoHS Compliant



BPW76 is a silicon NPN phototransistor with high radiant

sensitivity in hermetically sealed TO-18 package with base

terminal and flat glass window. It is sensitive to visible and

### FEATURES

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): Ø 4.7
- · High photo sensitivity
- High radiant sensitivity
- · Suitable for visible and near infrared radiation
- · Fast response times
- Angle of half sensitivity:  $\phi = \pm 40^{\circ}$
- · Base terminal connected
- Hermetically sealed package
- Flat glass window
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

## **APPLICATIONS**

· Detector in electronic control and drive circuits

# PRODUCT SUMMARY COMPONENT I<sub>ca</sub> (mA) φ (deg) λ<sub>0.1</sub> (nm) BPW76A 0.4 to 0.8 ± 40 450 to 1080 BPW76B > 0.6 ± 40 450 to 1080

#### Note

DESCRIPTION

near infrared radiation.

Test condition see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	PACKAGE FORM				
BPW76A	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18			
BPW76B	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18			

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Collector base voltage		V <sub>CBO</sub>	80	V	
Collector emitter voltage		V <sub>CEO</sub>	70	V	
Emitter base voltage		V <sub>EBO</sub>	5	V	
Collector current		Ι <sub>C</sub>	50	mA	
Collector peak current	$t_p/T=0.5,t_p\leq 10\;ms$	I <sub>CM</sub>	100	mA	
Total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	Pv	250	mW	
Junction temperature		Tj	125	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 125	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 125	°C	
Soldering temperature	$t \le 5 s$	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	400	K/W	
Thermal resistance junction/gase		R <sub>thJC</sub>	150	K/W	

#### Note

 $T_{amb}$  = 25 °C, unless otherwise specified





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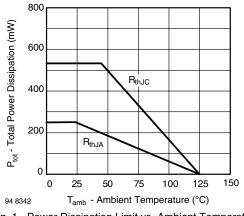


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	70			V
Collector emitter dark current	$V_{CE} = 20 V, E = 0$	I <sub>CEO</sub>		1	100	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz, E = 0	C <sub>CEO</sub>		6		pF
Angle of half sensitivity		φ		± 40		deg
Wavelength of peak sensitivity		λ <sub>p</sub>		850		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		450 to 1080		nm
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $I_C = 0.1 \text{ mA}$	V <sub>CEsat</sub>		0.15	0.3	V
Turn-on time	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	t <sub>on</sub>		6		μs
Turn-off time	$V_{S}$ = 5 V, $I_{C}$ = 5 mA, $R_{L}$ = 100 $\Omega$	t <sub>off</sub>		5		μs
Cut-off frequency	$V_S$ = 5 V, $I_C$ = 5 mA, $R_L$ = 100 $\Omega$	f <sub>c</sub>		110		kHz

#### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified

TYPE DEDICATED CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector light current	$\label{eq:eq:entropy} \begin{split} E_{e} = 1 \ mW/cm^2,  \lambda = 950 \ nm, \\ V_{CE} = 5 \ V \end{split}$	BPW76A	I <sub>ca</sub>	0.4		0.8	mA
		BPW76B	I <sub>ca</sub>	0.6			mA

## **BASIC CHARACTERISTICS**

 $T_{amb} = 25 \ ^{\circ}C$ , unless otherwise specified

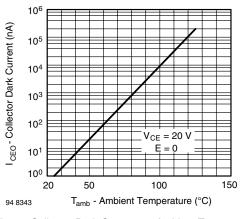


Fig. 2 - Collector Dark Current vs. Ambient Temperature

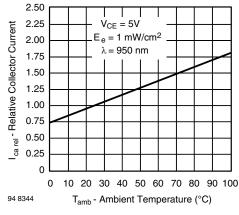


Fig. 3 - Relative Collector Current vs. Ambient Temperature

# BPW76A, BPW76B

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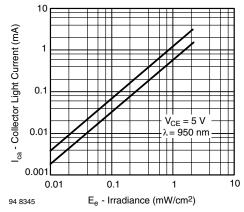


Fig. 4 - Collector Light Current vs. Irradiance

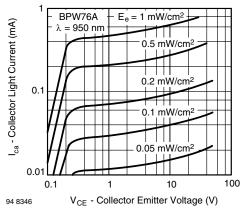


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

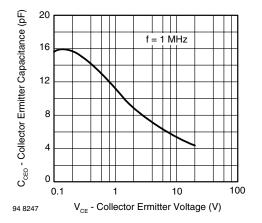


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

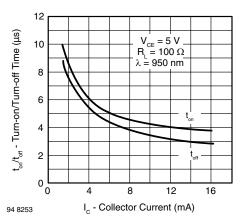


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

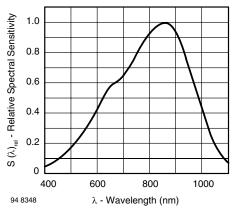


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

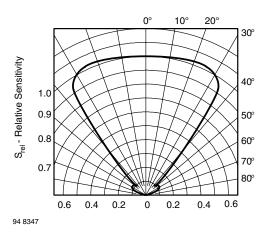


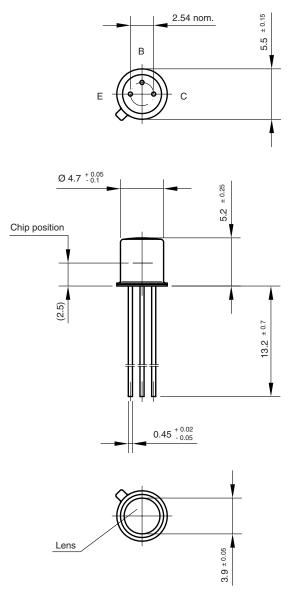
Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

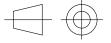


# BPW76A, BPW76B

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## **PACKAGE DIMENSIONS** in millimeters





technical drawings according to DIN specifications

Drawing-No.: 6.503-5004.01-4 Issue:1; 01.07.96 96 12175



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